

## NCE N-Channel Enhancement Mode Power MOSFET

#### **Description**

The NCE9926 uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

V<sub>DS</sub> =20V,I<sub>D</sub> =6A

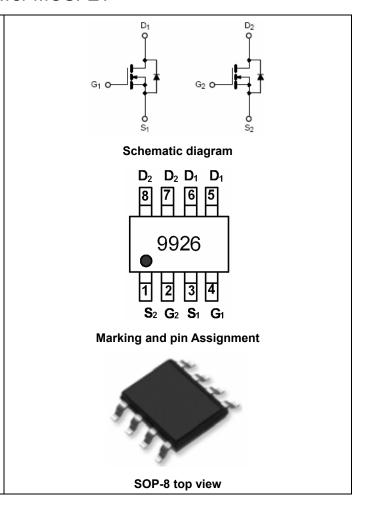
 $R_{DS(ON)} < 30 \text{m}\Omega$  @  $V_{GS} = 4.5 \text{V}$ 

 $R_{DS(ON)}$  < 40m $\Omega$  @  $V_{GS}$ =2.5V

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current

#### **Application**

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
9926	NCE9926	SOP-8	Ø330mm	12mm	2500 units

#### Absolute Maximum Ratings (TC=25°Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	20	V
Gate-Source Voltage	V <sub>GS</sub>	±10	V
Drain Current-Continuous	I <sub>D</sub>	6	А
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	3.8	А
Pulsed Drain Current	I <sub>DM</sub>	25	А
Maximum Power Dissipation	P <sub>D</sub>	1.25	W
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 150	$^{\circ}$ C

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	100	°C/W

## Electrical Characteristics (TC=25°Cunless otherwise noted)

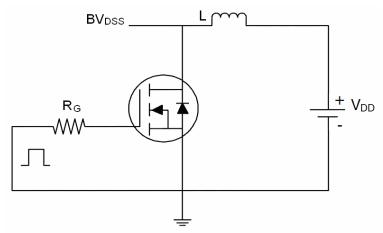
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•	•		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	20	22	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =20V,V <sub>GS</sub> =0V	-	-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±10V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)			•	•		
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA	0.5		1.2	V
Danier Courses On Otata Basistana		V <sub>GS</sub> =4.5V, I <sub>D</sub> =6A	-	26	30	0
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =2.5V, I <sub>D</sub> =5A	-	36	40	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =6A	20	-	-	S
Dynamic Characteristics (Note4)	1			I		
Input Capacitance	C <sub>lss</sub>	V <sub>DS</sub> =10V,V <sub>GS</sub> =0V,	-	640	-	PF
Output Capacitance	C <sub>oss</sub>		-	140	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	80	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	8	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =10 $V$ , $I_{D}$ =1 $A$	-	9	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GEN}$ =4.5 $V$ , $R_G$ =6 $\Omega$	-	15	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	4	-	nS
Total Gate Charge	Qg	\/ -40\/  -24	-	10	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =10V, $I_{D}$ =3A, $V_{GS}$ =4.5V	-	1.5	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	v <sub>GS</sub> -4.3v	-	1.6	_	nC
Drain-Source Diode Characteristics	<u> </u>		•		-	
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =1.7A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	6	Α

#### Notes:

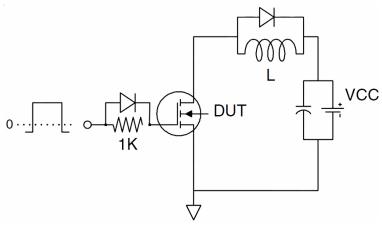
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production

## **Test Circuit**

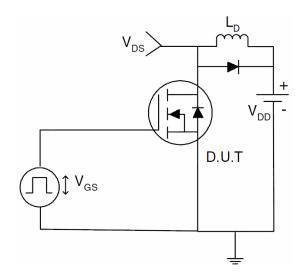
## 1) E<sub>AS</sub> Test Circuits



## 2) Gate Charge Test Circuit:



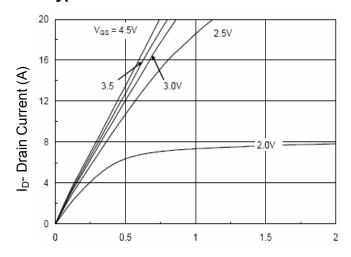
## 3) Switch Time Test Circuit:





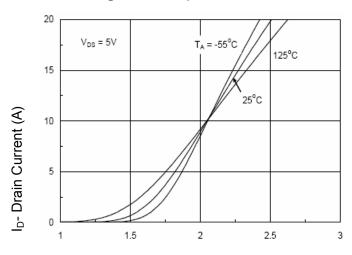
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## **Typical Electrical and Thermal Characteristics (Curves)**



Vds Drain-Source Voltage (V)

**Figure 1 Output Characteristics** 



Vgs Gate-Source Voltage (V)

**Figure 2 Transfer Characteristics** 

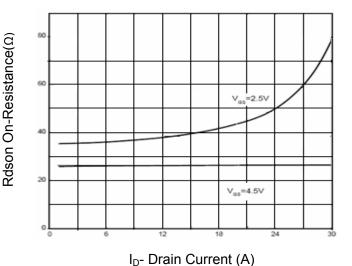


Figure 3 Rdson- Drain Current

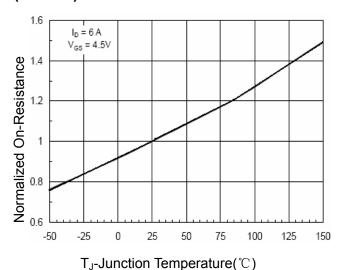
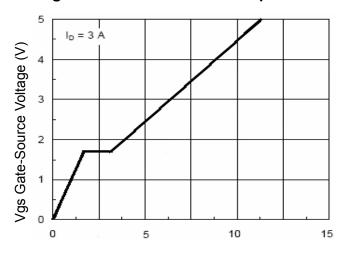
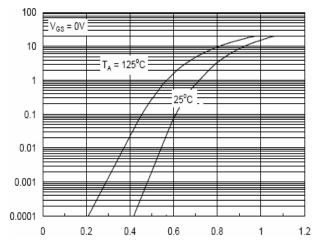


Figure 4 Rdson-JunctionTemperature



Qg Gate Charge (nC)
Figure 5 Gate Charge

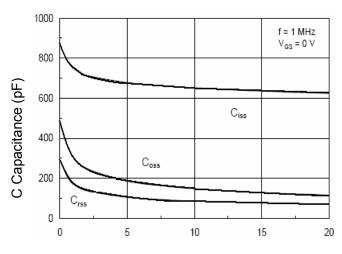


Vsd Source-Drain Voltage (V)

Figure 6 Source- Drain Diode Forward

TJ(°C)





Vds Drain-Source Voltage (V)

Figure 7 Capacitance vs Vds

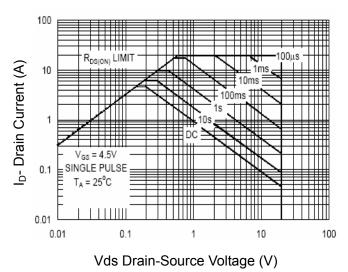


Figure 8 Safe Operation Area

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BVDSS

Normalized BVdss

 $T_J$ -Junction Temperature( $^{\circ}$ C)

Figure 9 BV<sub>DSS</sub> vs Junction Temperature

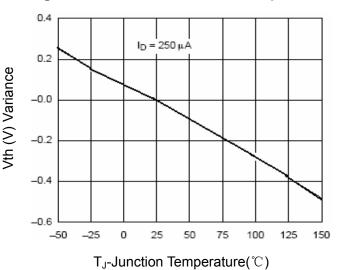
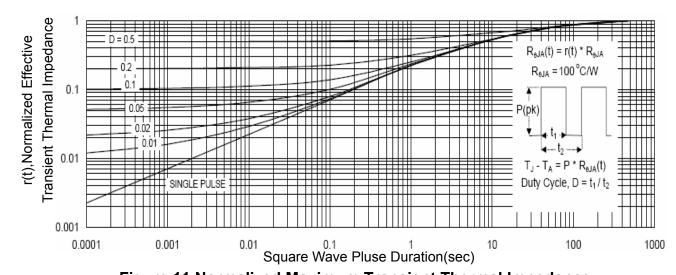


Figure 10 V<sub>GS(th)</sub> vs Junction Temperature

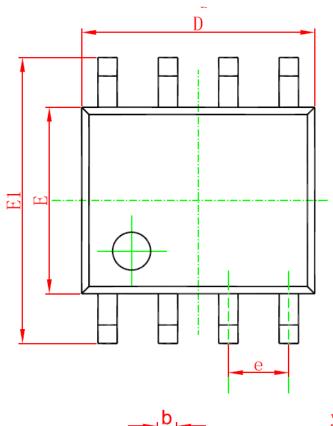


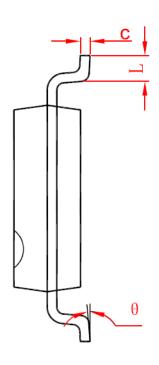
**Figure 11 Normalized Maximum Transient Thermal Impedance** 

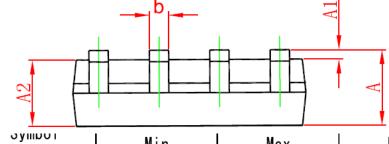
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## **SOP-8 Package Information**







o y III DO I	Min	Max	Min	Max	
Comb a l	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	1. 350	1. 750	0. 053	0. 069	
A1	0. 100	0. 250	0. 004	0. 010	
A2	1. 350	1. 550	0. 053	0. 061	
b	0. 330	0. 510	0. 013	0. 020	
С	0. 170	0. 250	0. 006	0. 010	
D	4. 700	5. 100	0. 185	0. 200	
E	3. 800	4. 000	0. 150	0. 157	
E1	5. 800	6. 200	0. 228	0. 244	
е	1. 270 (BSC)		0. 050 (BSC)		
L	0. 400	1. 270	0. 016	0. 050	
θ	0°	8°	0°	8°	



#### http://www.ncepower.com

NCE9926

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